

SPECIFICATION

Device Name : Power Integrated Module

Type Name : 7 M B R 2 5 S A 1 4 0

Spec. No. : M S 6 M 0 4 7 3

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Fuji Electric Co., Ltd.
Matsumoto Factory



找PDF	DATE	NAME	APPROVED
DRAWN	Nov. -10 -'99	T. Kufayashiki	
CHECKED	Nov. -10 -'99	S. M. K. A.	

Fuji Electric Co., Ltd.			
FIG. NO.	M S 6 M 0 4 7 3	1	

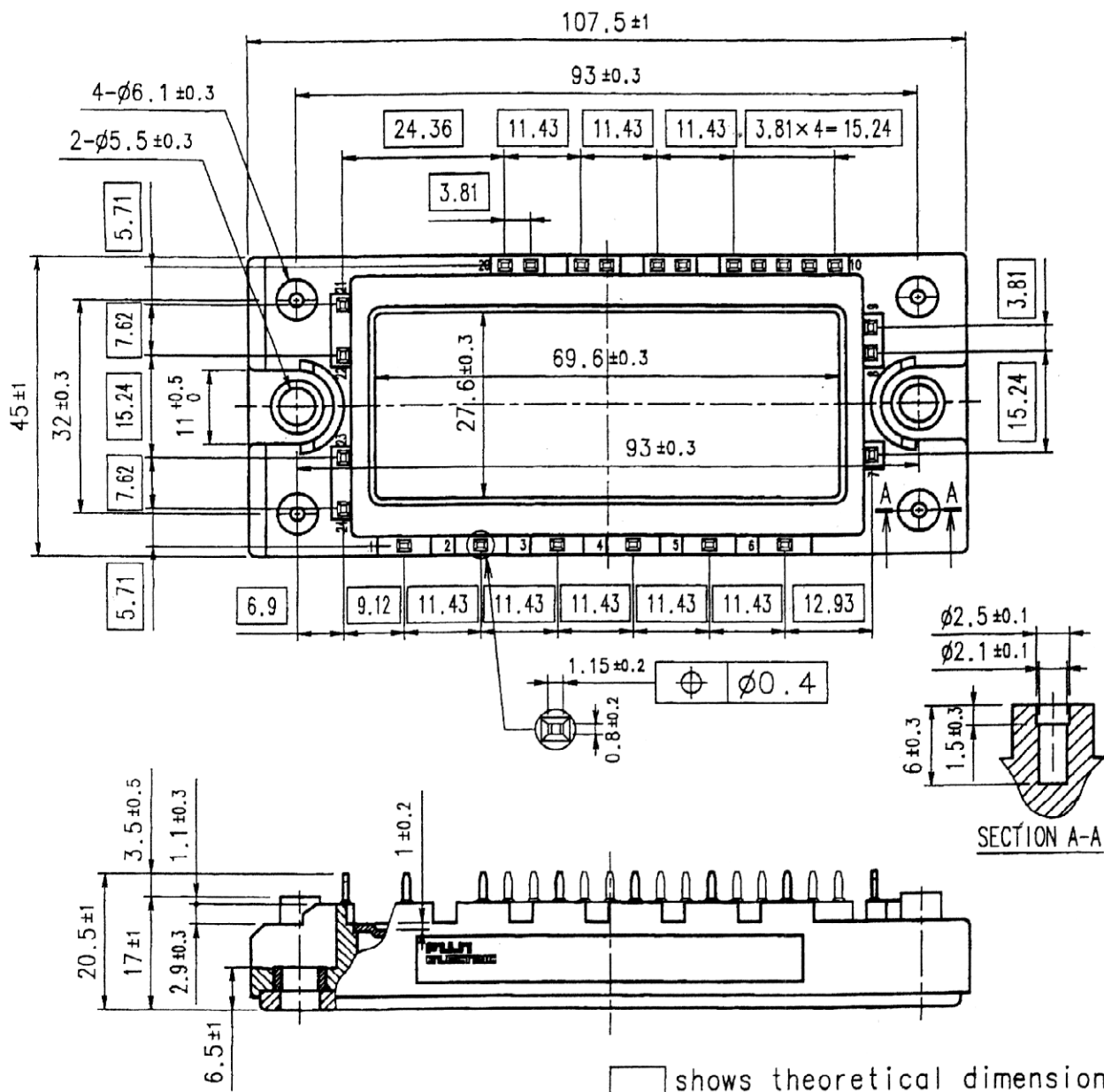
Revised Records

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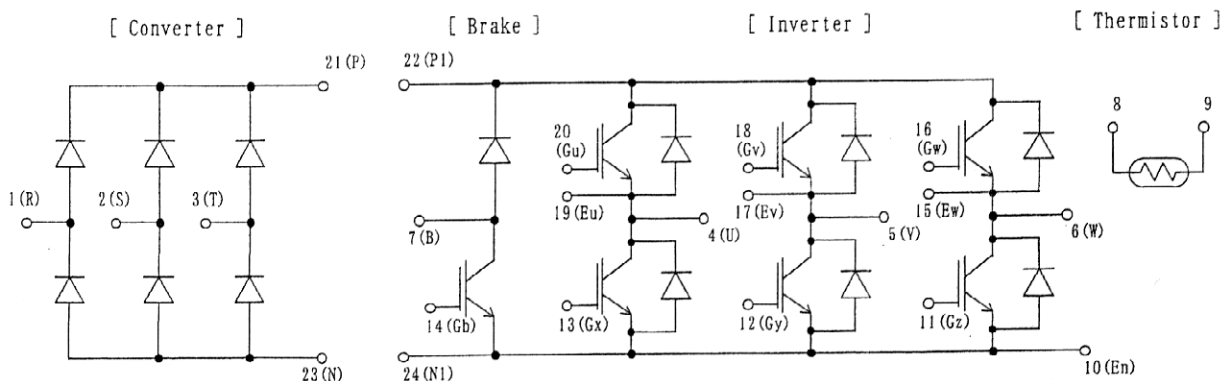
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7 MBR 2 5 S A 1 4 0

1. Outline Drawing (Unit : mm)



2. Equivalent circuit



3. Absolute Maximum Ratings (at Tc= 25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			±20	V
	Collector current	Ic	Continuous	Tc=25°C	35	A
				Tc=75°C	25	
		Icp	1ms	Tc=25°C	70	A
				Tc=75°C	50	
		-Ic			25	A
Collector Power Dissipation		Pc	1 device		180	W
Brake	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			±20	V
	Collector current	Ic	Continuous	Tc=25°C	25	A
				Tc=75°C	15	
		Icp	1ms	Tc=25°C	50	A
				Tc=75°C	30	
	Collector Power Dissipation	Pc	1 device		110	W
Repetitive peak reverse Voltage(Diode)		VRRM			1400	V
Converter	Repetitive peak reverse Voltage	VRRM			1600	V
	Average Output Current	Io	50Hz/60Hz sine wave		25	A
	Surge Current (Non-Repetitive)	IFSM	Tj=150°C, 10ms		260	A
	I ² t (Non-Repetitive)	I ² t	half sine wave		338	A ² s
	Junction temperature	Tj			150	°C
Storage temperature		Tstg			-40~ +125	°C
Isolation voltage	between terminal and copper base ^(*1)	Viso	AC : 1min.		2500	V
	between thermistor and others ^(*2)				2500	V
Mounting Screw Torque ^(*3)					3.5	N・m

(*1) All terminals should be connected together when isolation test will be done.

(*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*3) Recommendable Value : 2.5~3.5 N・m (M5)

4. Electrical characteristics (at Tj = 25°C unless otherwise specified)

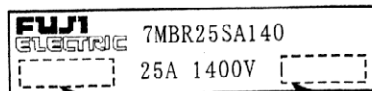
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES VGE = 0 V, VCE = 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES VCE = 0 V, VGE = ±20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th) VCE = 20 V, Ic = 25 mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat) VGE = 15 V, chip Ic = 25 A terminal		2.2		V
				2.3	2.7	
	Input capacitance	Cies VGE = 0 V, VCE = 10 V f = 1 MHz		3000		pF
	Turn-on time	Vcc = 800 V Ic = 25 A VGE = ±15 V		0.35	1.2	μs
				0.25	0.6	
				0.1		
	Turn-off time	RG = 51 Ω		0.45	1.0	
				0.08	0.3	
	Forward on voltage	VF IF = 25 A chip terminal		2.4		V
				2.5	3.3	
	Reverse recovery time	trr IF = 25 A			350	ns
Brake	Zero gate voltage Collector current	ICES VGE = 0 V, VCE = 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES VCE = 0 V, VGE = ±20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat) VGE = 15 V, chip Ic = 15 A terminal		2.2		V
				2.3	2.7	
	Turn-on time	Vcc = 800 V Ic = 15 A		0.35	1.2	μs
				0.25	0.6	
	Turn-off time	VGE = ±15 V RG = 82 Ω		0.45	1.0	
				0.08	0.3	
	Reverse current	IRRM VR = 1400 V			1.0	mA
Converter	Forward on voltage	VFM IF = 25 A chip terminal		1.1		V
				1.2	1.5	
	Reverse current	IRRM VR = 1600 V			1.0	mA
Thermistor	Resistance	R T = 25°C T = 100°C		5000		Ω
			465	495	520	
	B value	B T = 25/50°C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.69	°C/W
		Inverter FWD			1.30	
		Brake IGBT			1.14	
		Converter Diode			0.90	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (※)		0.05		°C/W

※ This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module (モジュール表示)



Lot No.

Place of manufacturing (code)

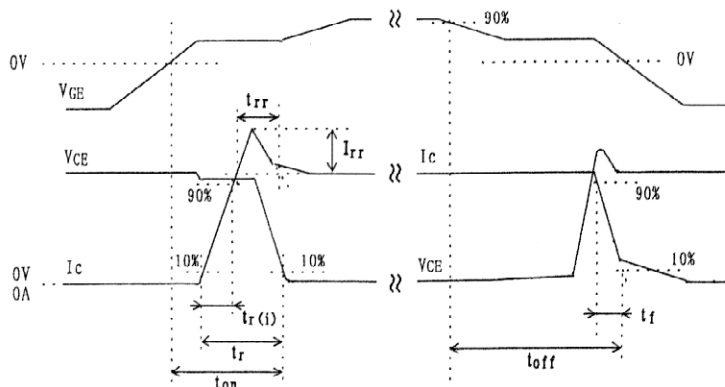
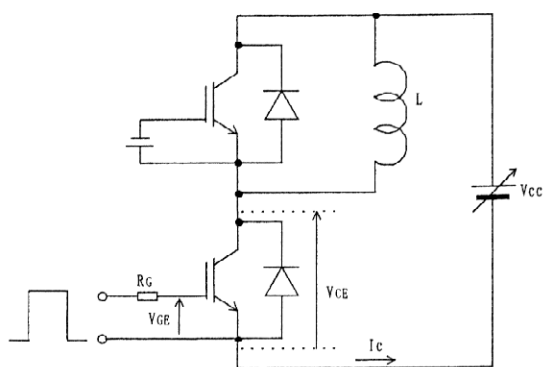
7. Applicable category (適用範囲)

This specification is applied to Power Integrated Module named 7MBR25SA140.
本納入仕様書は パワー集積モジュール 7MBR25SA140 に適用する。

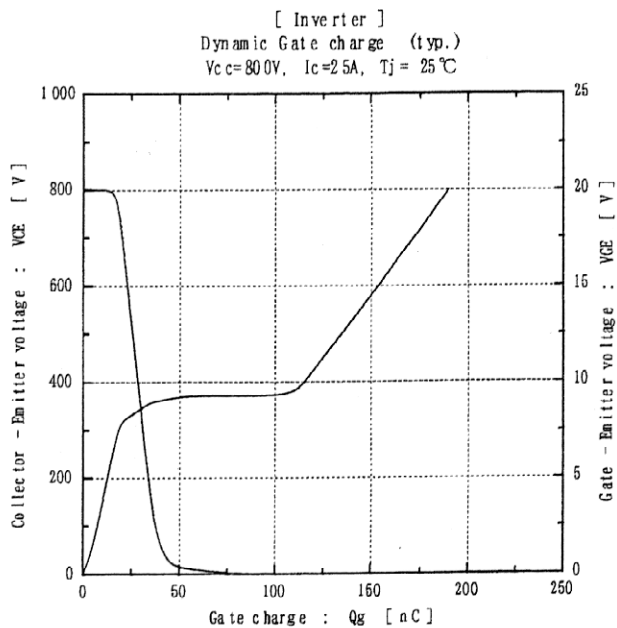
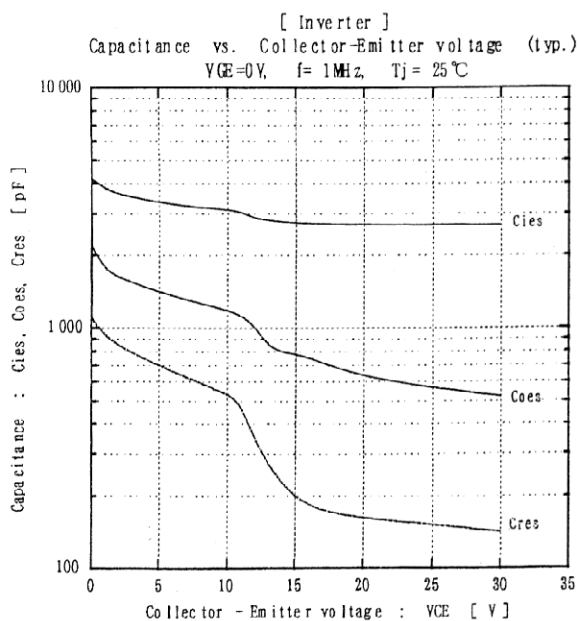
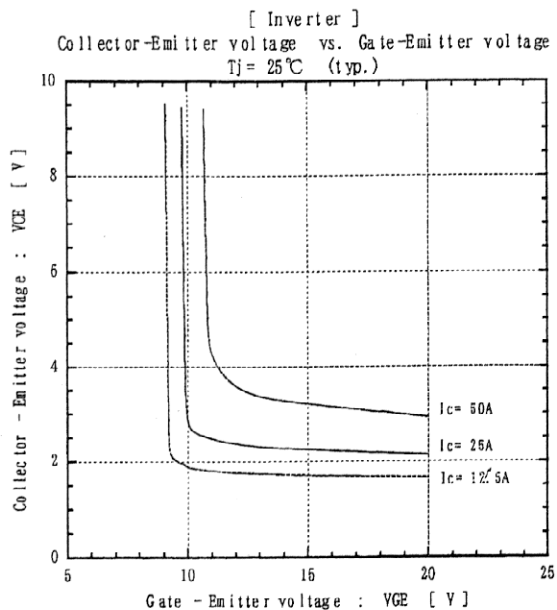
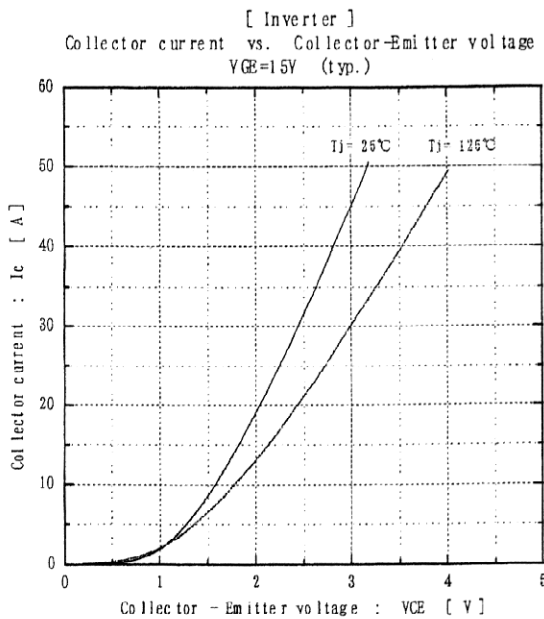
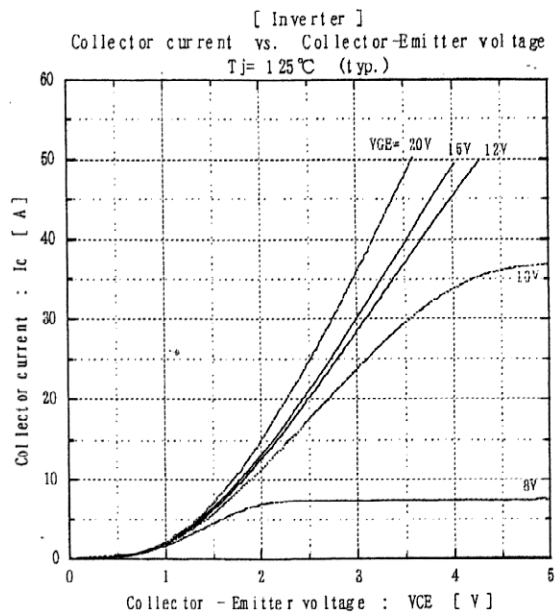
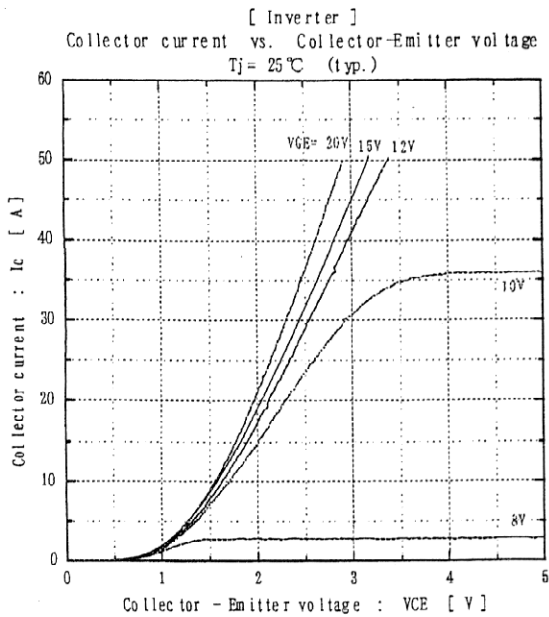
8. Storage and transportation notes (保管・運搬上の注意事項)

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75%.
常温・常湿保存が望ましい。(5~35°C, 45~75%)
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
急激な温度変化のなきこと。(モジュール表面が結露しないこと)
- Avoid exposure to corrosive gases and dust.
腐蝕性ガスの発生場所, 塵埃の多い場所は避けること。
- Avoid excessive external force on the module.
製品に荷重がかからないように 十分注意すること。
- Store modules with unprocessed terminals.
モジュールの端子は未加工の状態 で保管すること。
- Do not drop or otherwise shock the modules when transporting.
製品の運搬時に衝撃を与えたり, 落下させたりしないこと。

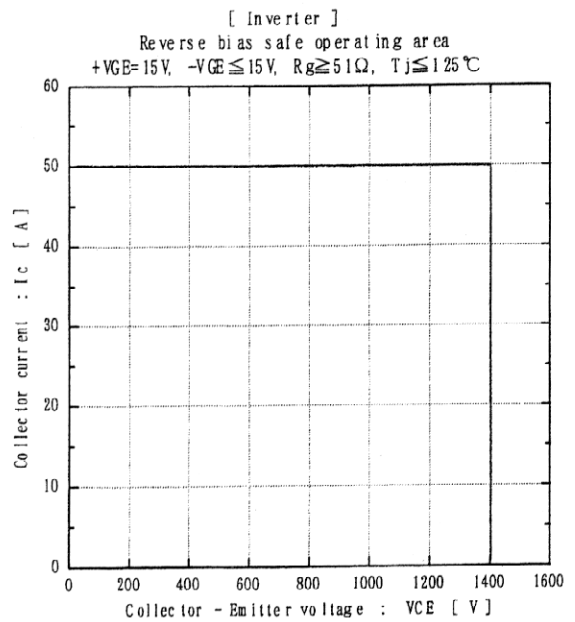
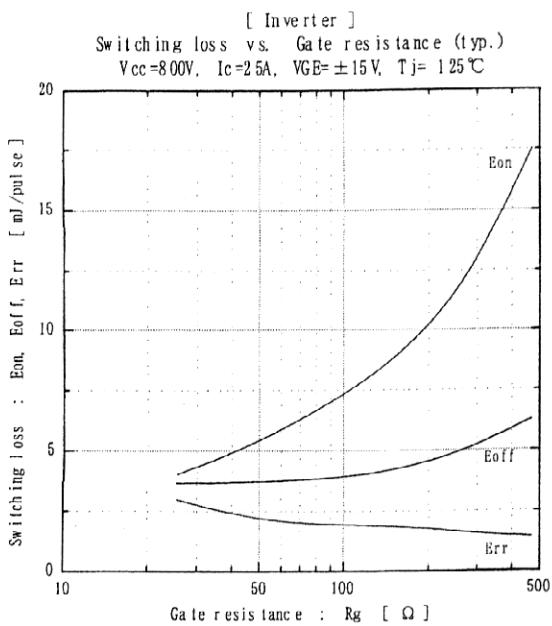
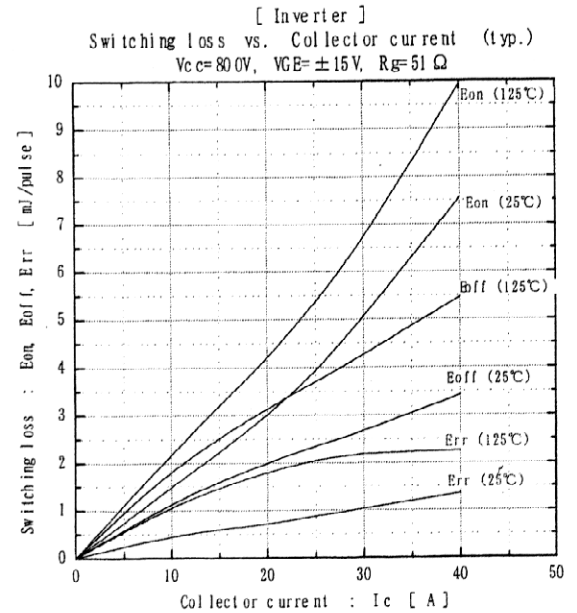
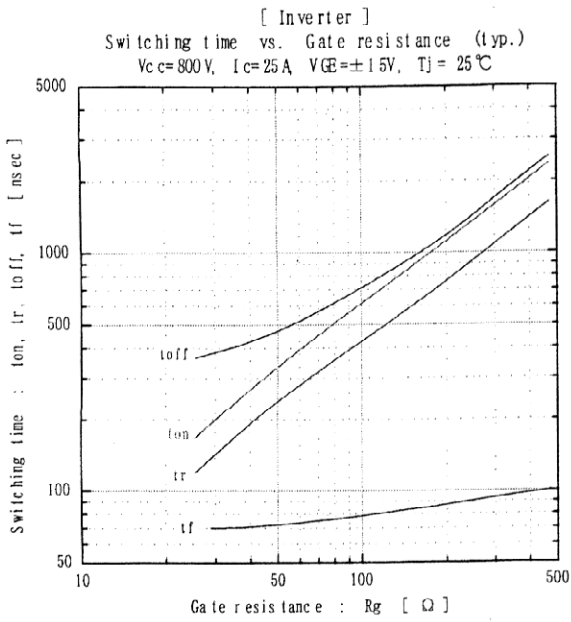
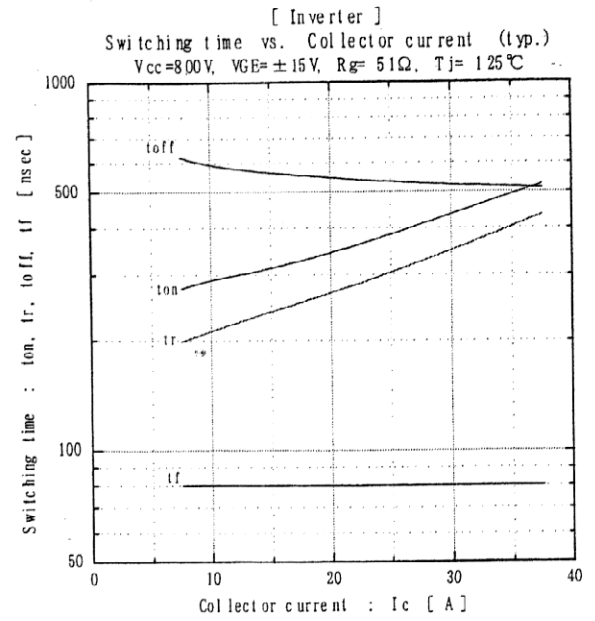
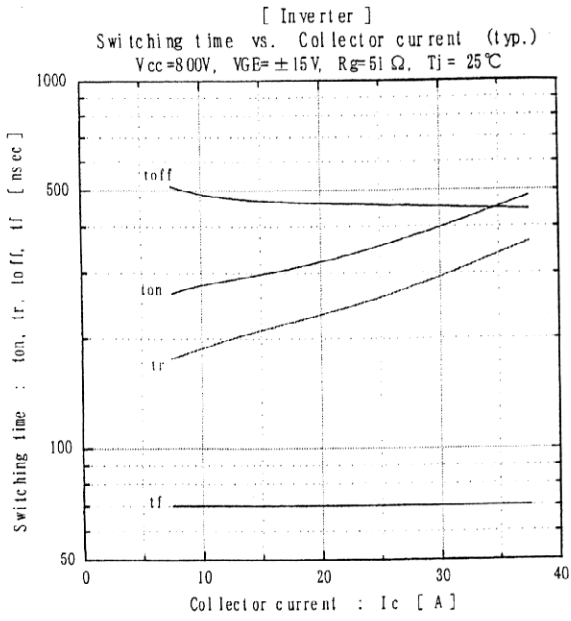
9. Definitions of switching time (スイッチング時間の定義)



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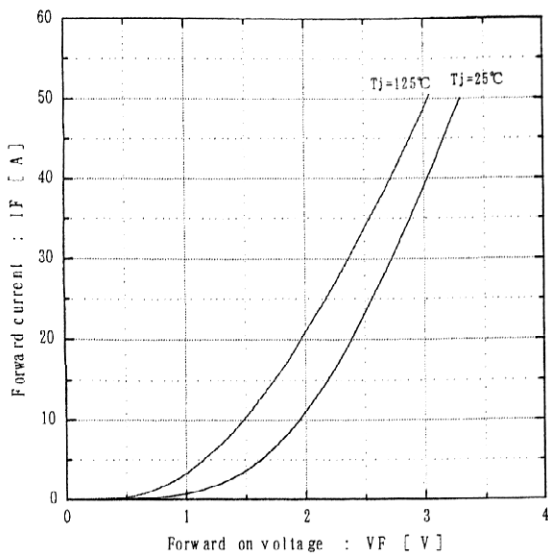


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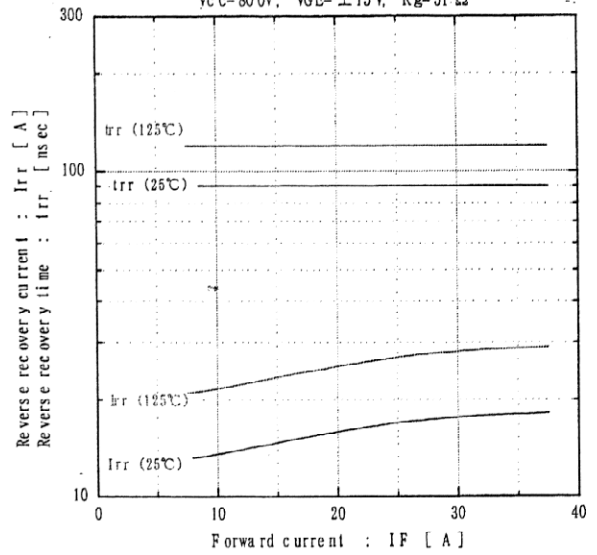


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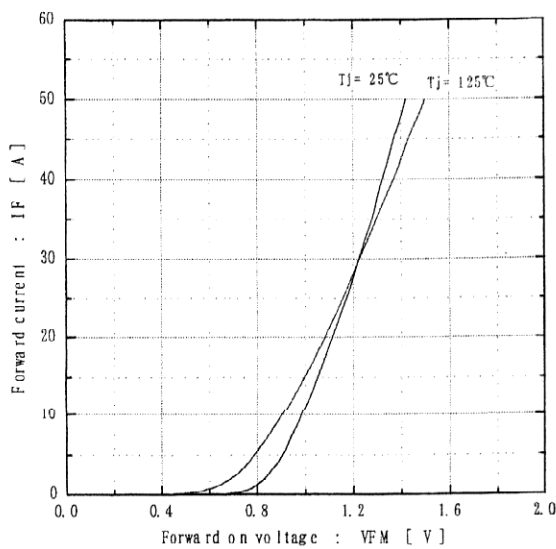
[Inverter]
Forward current vs. Forward on voltage (typ.)



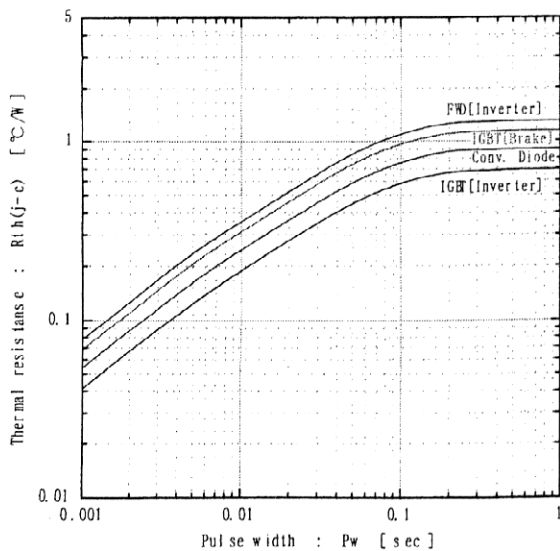
[Inverter]
Reverse recovery characteristics (typ.)
Vcc = 80.0V, VGE = ±15V, RG = 51Ω



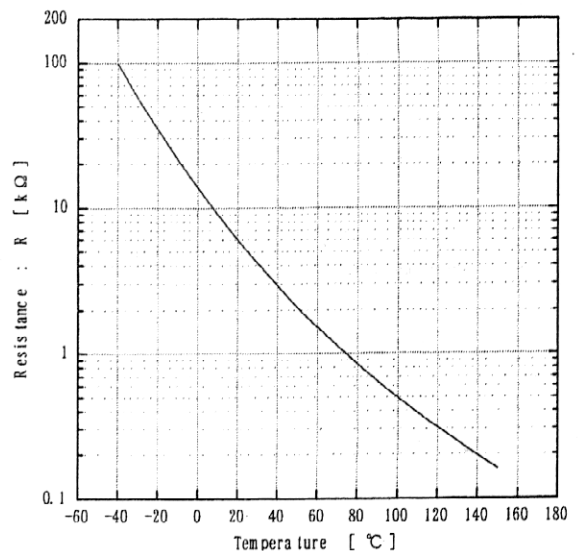
[Converter]
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[Thermistor]
Temperature characteristic (typ.)



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